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WE CLAIM:

1. A photovoltaic device comprising a n-type semiconductor with a band-gap of greater than 2.9 eV and a 1,3,5-tris-aminophenylbenzene compound represented by formula (I):

$$R^{\frac{1}{2}}$$
 $R^{\frac{1}{2}}$
 $R^{\frac{1}{2}}$

wherein R^1 represents a $-NR^3R^4$ group, wherein R^3 and R^4 , same or different, represent an unsubstituted C_2 - C_{10} alkyl group, a substituted C_2 - C_{10} alkyl group, a benzyl group, an unsubstituted cycloalkyl group, a substituted cycloalkyl group, an unsubstituted aryl group or a substituted aryl group, and R^2 represents hydrogen, an alkyl group including a substituted alkyl group or halogen; and said 1,3,5-tris-aminophenyl-benzene compound is in a cationic form.

2. Photovoltaic device according to claim 1, wherein said 1,3,5-tris-aminophenyl-benzene compound represented by formula (I) is selected from the group consisting of the cations of:

$$\begin{array}{c} H_5C_2 \\ \\ \\ C_2H_5 \\ \\ C_2H_5 \\ \\ \end{array} \begin{array}{c} C_2H_5 \\ \\ \\ C_2H_5 \\ \\ \end{array} \begin{array}{c} C_2H_5 \\ \\ \\ C_2H_5 \\ \\ \end{array} \begin{array}{c} C_2H_5 \\ \\ \\ \end{array} \begin{array}{c} C_2$$

- -

and

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- 3. Photovoltaic device according to claim 1, wherein said n-type semiconductor is selected from the group consisting of titanium oxides, tin oxides, niobium oxides, tantalum oxides, tungsten oxides and zinc oxides.
- 4. Photovoltaic device according to claim 1, wherein said photovoltaic device further contains at least one spectral sensitizer.
- 5. Photovoltaic device according to claim 1, wherein said photovoltaic device further contains at least one spectral sensitizer selected from the group consisting of metal chalcogenide nano-particles with a band-gap of less than 2.9 eV, organic dyes and metallo-organic dyes.
 - 6. Photovoltaic device according to claim 1, wherein said photovoltaic device further contains at least one spectral sensitizer selected from the group consisting metal oxides, metal sulphides and metal selenides.

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7. A process for preparing a photovoltaic device comprising a n-type semiconductor with a band-gap of greater than 2.9 eV and a 1,3,5-tris-aminophenyl-benzene compound represented by formula (I):

$$R^{2}$$
 R^{1}
 R^{2}
 R^{1}

wherein R¹ represents a -NR³R⁴ group, wherein R³ and R⁴, same or different, represent an unsubstituted C2-C10 alkyl group, a substituted C_2 - C_{10} alkyl group, a benzyl group, an unsubstituted cycloalkyl group, a substituted cycloalkyl group, an unsubstituted aryl group or a substituted aryl group, and R² represents hydrogen, an alkyl group including a substituted alkyl group or halogen, and said 1,2,5-tris-aminophenyl-benzene compound is in a cationic form, with at least one transparent electrode comprising the steps of: providing a support with a conductive layer as one electrode; coating said conductive layer on the support with a layer comprising said n-type semiconductor with a bandgap of greater than 2.9 eV; coating said n-type semiconductor-containing layer with a solution or dispersion comprising a cation of said 1,3,5-tris-aminophenyl-benzene compound to provide after drying a layer comprising said 1,3,5tris-aminophenyl-benzene compound; and applying a conductive layer to said layer comprising said 1,3,5-tris-aminophenylbenzene compound thereby providing a second electrode.

8. A photovoltaic device comprising a n-type semiconductor with a band-gap of greater than 2.9 eV and a 1,3,5-tris-aminophenyl-benzene compound represented by formula (I):

$$R^{1}$$
 R^{2}
 R^{1}
 R^{2}
 R^{1}

wherein R^1 represents a $-NR^3R^4$ group, wherein R^3 and R^4 , same or different, represent an unsubstituted C_2 - C_{10} alkyl group, a substituted C_2 - C_{10} alkyl group, a benzyl group, an unsubstituted cycloalkyl group, a substituted cycloalkyl group, an unsubstituted aryl group or a substituted aryl group, and R^2 represents hydrogen, an alkyl group including a substituted alkyl group or halogen; and said 1,3,5-tris-aminophenyl-benzene compound.

9. Photovoltaic device according to claim 8, wherein said 1,3,515 tris-aminophenyl-benzene compound represented by formula (I) is selected from the group consisting of:

$$H_sC_2$$
 C_2H_s
 C_2H_s
 C_2H_s

and

10. Photovoltaic device according to claim 8, wherein said n-type semiconductor is selected from the group consisting of titanium oxides, tin oxides, niobium oxides, tantalum oxides, tungsten oxides and zinc oxides.

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- 11. Photovoltaic device according to claim 8, wherein said photovoltaic device further contains at least one spectral sensitizer.
- 12. Photovoltaic device according to claim 8, wherein said photovoltaic device further contains at least one spectral sensitizer selected from the group consisting of metal chalcogenide nano-particles with a band-gap of less than 2.9 eV, organic dyes and metallo-organic dyes.
- 13. Photovoltaic device according to claim 8, wherein said photovoltaic device further contains at least one spectral sensitizer selected from the group consisting metal oxides, metal sulphides and metal selenides.
 - 14. A process for preparing a photovoltaic device comprising a n-type semiconductor with a band-gap of greater than 2.9 eV and a 1,3,5-tris-aminophenyl-benzene compound represented by formula (I):

$$R^{\frac{1}{2}}$$
 $R^{\frac{1}{2}}$
 $R^{\frac{1}{2}}$

wherein R^1 represents a $-NR^3R^4$ group, wherein R^3 and R^4 , same or different, represent an unsubstituted C_2 - C_{10} alkyl group, a substituted C_2 - C_{10} alkyl group, a benzyl group, an unsubstituted cycloalkyl group, as substituted cycloalkyl group, an unsubstituted aryl group or a substituted aryl group, and R^2 represents hydrogen, an alkyl group including a substituted alkyl group or halogen with at least one transparent electrode comprising the steps of: providing a support with a conductive layer as one electrode; coating said conductive layer on the support with a layer comprising said n-type semiconductor with a bandgap of greater than 2.9 eV; coating said n-type semiconductor-containing layer with a solution or dispersion

comprising said 1,3,5-tris-aminophenyl-benzene compound to provide after drying a layer comprising said 1,3,5-tris-aminophenyl-benzene compound; and applying a conductive layer to said layer comprising said 1,3,5-tris-aminophenyl-benzene compound thereby providing a second electrode.